74HC273; 74HCT273

Octal D-type flip-flop with reset; positive-edge trigger

Rev. 03 — 24 January 2006 Product data sheet

1. General description

The 74HC273; 74HCT273 is a high-speed Si-gate CMOS device and is pin compatible with Low-power Schottky TTL (LSTTL).

The 74HC273; 74HCT273 has eight edge-triggered, D-type flip-flops with individual D inputs and Q outputs. The common clock (pin CP) and master reset (pin $\overline{MR}$) inputs load and reset (clear) all flip-flops simultaneously. The state of each D input, one set-up time before the LOW-to-HIGH clock transition, is transferred to the corresponding output (Qn) of the flip-flop.

All outputs will be forced LOW independently of clock or data inputs by a LOW voltage level on the $\overline{MR}$ input.

The device is useful for applications where the true output only is required and the clock and master reset are common to all storage elements.

2. Features

- Ideal buffer for MOS microprocessor or memory
- Common clock and master reset
- Eight positive edge-triggered D-type flip-flops
- Complies with JEDEC standard no. 7A
- ESD protection:
  - HBM EIA/JESD22-A114-C exceeds 2000 V
  - MM EIA/JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from –40 °C to +85 °C and from –40 °C to +125 °C

3. Quick reference data

Table 1: Quick reference data

GND = 0 V; T_{amb} = 25 °C; $t_r = t_f$ = 6 ns.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
74HC273						
t_{PHL}, t_{PLH}	propagation delay CP to Qn	V_{CC} = 5 V; C_L = 15 pF	-	15	-	ns
t_{PHL}	HIGH-to-LOW propagation delay $\overline{MR}$ to Qn	V_{CC} = 5 V; C_L = 15 pF	-	15	-	ns
f_{max}	maximum input clock frequency	V_{CC} = 5 V; C_L = 15 pF	-	66	-	MHz

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Table 1: Quick reference data *...continued*

GND = 0 V; T_{amb} = 25 °C; $t_r = t_f$ = 6 ns.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
C_i	input capacitance			-	3.5	-	pF
C_{PD}	power dissipation capacitance	per flip-flop; V_I = GND to V_{CC}	[1]	-	20	-	pF
74HCT273							
t_{PHL}, t_{PLH}	propagation delay CP to Qn	V_{CC} = 5 V; C_L = 15 pF		-	15	-	ns
t_{PHL}	HIGH-to-LOW propagation delay $\overline{MR}$ to Qn	V_{CC} = 5 V; C_L = 15 pF		-	20	-	ns
f_{max}	maximum input clock frequency	V_{CC} = 5 V; C_L = 15 pF		-	36	-	MHz
C_i	input capacitance			-	3.5	-	pF
C_{PD}	power dissipation capacitance	per flip-flop; V_I = GND to (V_{CC} – 1.5 V)	[1]	-	23	-	pF

[1] C_{PD} is used to determine the dynamic power dissipation (P_D in µW).
$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:
f_i = input frequency in MHz;
f_o = output frequency in MHz;
C_L = output load capacitance in pF;
V_{CC} = supply voltage in V;
N = number of inputs switching;
$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

4. Ordering information

Table 2: Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC273				
74HC273N	–40 °C to +125 °C	DIP20	plastic dual in-line package; 20 leads (300 mil)	SOT146-1
74HC273D	–40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1
74HC273DB	–40 °C to +125 °C	SSOP20	plastic shrink small outline package; 20 leads; body width 5.3 mm	SOT339-1
74HC273PW	–40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1
74HC273BQ	–40 °C to +125 °C	DHVQFN20	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 × 4.5 × 0.85 mm	SOT764-1
74HCT273				
74HCT273N	–40 °C to +125 °C	DIP20	plastic dual in-line package; 20 leads (300 mil)	SOT146-1
74HCT273D	–40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1

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Table 2: Ordering information *…continued*

Type number	Package			
	Temperature range	Name	Description	Version
74HCT273DB	–40 °C to +125 °C	SSOP20	plastic shrink small outline package; 20 leads; body width 5.3 mm	SOT339-1
74HCT273PW	–40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1
74HCT273BQ	–40 °C to +125 °C	DHVQFN20	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 × 4.5 × 0.85 mm	SOT764-1

5. Functional diagram

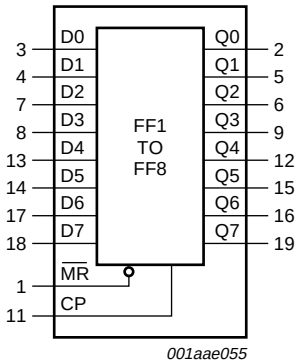


Fig 1. Functional diagram

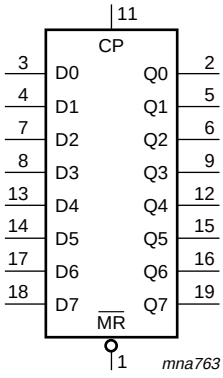


Fig 2. Logic symbol

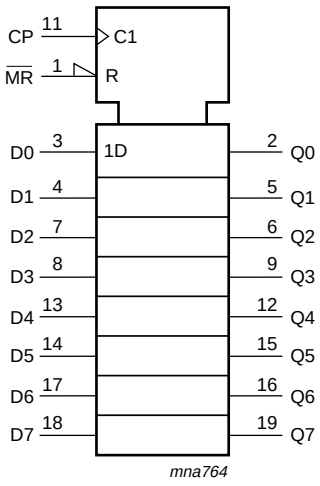


Fig 3. IEC logic symbol

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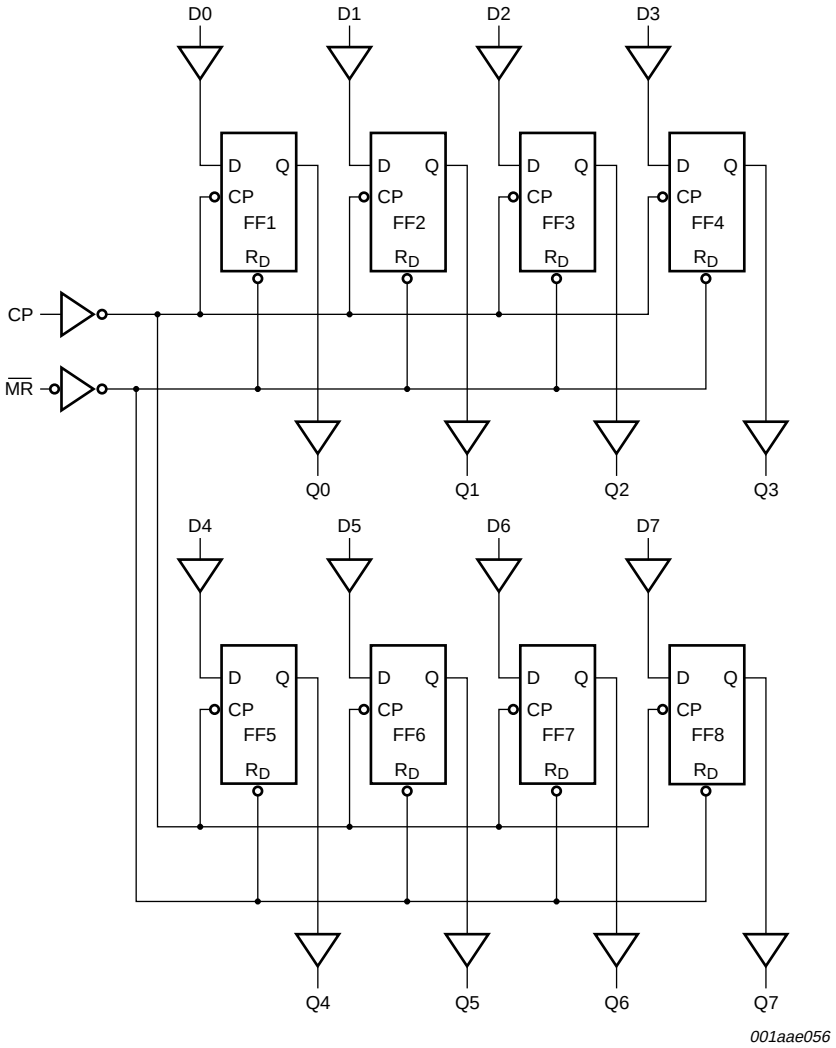


Fig 4. Logic diagram

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6. Pinning information

6.1 Pinning

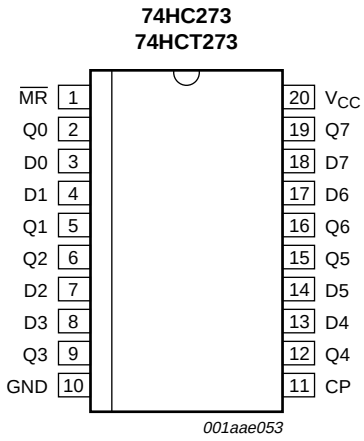
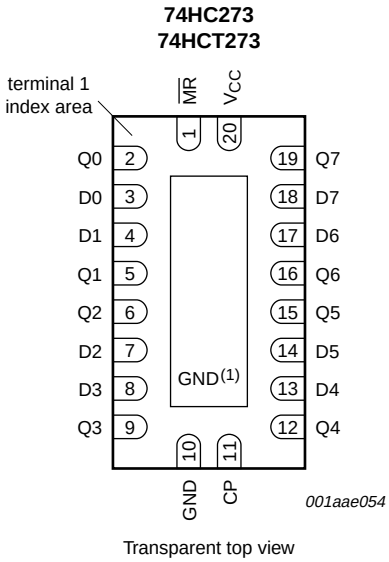


Fig 5. Pin configuration DIP20, SO20, SSOP20 and TSSOP20



Transparent top view

(1) The die substrate is attached to this pad using conductive die attach material. It can not be used as supply pin or output.

Fig 6. Pin configuration DHVQFN20

6.2 Pin description

Table 3: Pin description

Symbol	Pin	Description
$\overline{MR}$	1	master reset input (active LOW)
Q0	2	flip-flop output 0
D0	3	data input 0
D1	4	data input 1
Q1	5	flip-flop output 1
Q2	6	flip-flop output 2
D2	7	data input 2
D3	8	data input 3
Q3	9	flip-flop output 3
GND	10	ground (0 V)
CP	11	clock input (LOW-to-HIGH, edge-triggered)
Q4	12	flip-flop output 4
D4	13	data input 4
D5	14	data input 5

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Table 3: Pin description *...continued*

Symbol	Pin	Description
Q5	15	flip-flop output 5
Q6	16	flip-flop output 6
D6	17	data input 6
D7	18	data input 7
Q7	19	flip-flop output 7
V_{CC}	20	supply voltage

7. Functional description

7.1 Function table

Table 4: Function table [1]

Operating modes	Control		Input	Output
	$\overline{MR}$	CP	Dn	Qn
Reset (clear)	L	X	X	L
Load 1	H	↑	h	H
Load 0	H	↑	l	L

[1] H = HIGH voltage level;
h = HIGH voltage level one set-up time prior to the LOW-to-HIGH CP transition;
L = LOW voltage level;
l = LOW voltage level one set-up time prior to the LOW-to-HIGH CP transition;
↑ = LOW-to-HIGH transition;
X = don't care.

8. Limiting values

Table 5: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		–0.5	+7	V
I_{IK}	input clamping current	$V_I < –0.5$ V or $V_I > V_{CC} + 0.5$ V	-	±20	mA
I_{OK}	output clamping current	$V_O < –0.5$ V or $V_O > V_{CC} + 0.5$ V	-	±20	mA
I_O	output current	$V_O = –0.5$ V to $(V_{CC} + 0.5$ V)	-	±25	mA
I_{CC}	quiescent supply current		-	50	mA
I_{GND}	ground current		-	–50	mA
T_{stg}	storage temperature		–65	+150	°C

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Table 5: Limiting values *…continued*

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
P_{tot}	total power dissipation					
	DIP20 package		[1]	-	750	mW
	SO20 package		[2]	-	500	mW
	SSOP20 package		[3]	-	500	mW
	TSSOP20 package		[3]	-	500	mW
	DHVQFN20 package		[4]	-	500	mW

[1] For DIP20 package: P_{tot} derates linearly with 12 mW/K above 70 °C.

[2] For SO20 package: P_{tot} derates linearly with 8 mW/K above 70 °C.

[3] For SSOP20 and TSSOP20 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

[4] For DHVQFN20 packages: P_{tot} derates linearly with 4.5 mW/K above 60 °C.

9. Recommended operating conditions

Table 6: Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
74HC273						
V_{CC}	supply voltage		2.0	5.0	6.0	V
V_I	input voltage		0	-	V_{CC}	V
V_O	output voltage		0	-	V_{CC}	V
T_{amb}	ambient temperature		–40	+25	+125	°C
t_r, t_f	input rise and fall time	V_{CC} = 2.0 V	-	-	1000	ns
		V_{CC} = 4.5 V	-	6.0	500	ns
		V_{CC} = 6.0 V	-	-	400	ns
74HCT273						
V_{CC}	supply voltage		4.5	5.0	5.5	V
V_I	input voltage		0	-	V_{CC}	V
V_O	output voltage		0	-	V_{CC}	V
T_{amb}	ambient temperature		–40	+25	+125	°C
t_r, t_f	input rise and fall time	V_{CC} = 4.5 V	-	6.0	500	ns

10. Static characteristics

Table 7: Static characteristics 74HC273

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = 25 °C						
V_{IH}	HIGH-state input voltage	V_{CC} = 2.0 V	1.5	1.2	-	V
		V_{CC} = 4.5 V	3.15	2.4	-	V
		V_{CC} = 6.0 V	4.2	3.2	-	V

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Table 7: Static characteristics 74HC273 *...continued*

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{IL}	LOW-state input voltage	V_{CC} = 2.0 V	-	0.8	0.5	V
		V_{CC} = 4.5 V	-	2.1	1.35	V
		V_{CC} = 6.0 V	-	2.8	1.8	V
V_{OH}	HIGH-state output voltage	$V_I = V_{IH}$ or V_{IL}				
		I_O = –20 µA; V_{CC} = 2.0 V	1.9	2.0	-	V
		I_O = –20 µA; V_{CC} = 4.5 V	4.4	4.5	-	V
		I_O = –20 µA; V_{CC} = 6.0 V	5.9	6.0	-	V
		I_O = –4.0 mA; V_{CC} = 4.5 V	3.98	4.32	-	V
		I_O = –5.2 mA; V_{CC} = 6.0 V	5.48	5.81	-	V
V_{OL}	LOW-state output voltage	$V_I = V_{IH}$ or V_{IL}				
		I_O = 20 µA; V_{CC} = 2.0 V	-	0	0.1	V
		I_O = 20 µA; V_{CC} = 4.5 V	-	0	0.1	V
		I_O = 20 µA; V_{CC} = 6.0 V	-	0	0.1	V
		I_O = 4.0 mA; V_{CC} = 4.5 V	-	0.15	0.26	V
		I_O = 5.2 mA; V_{CC} = 6.0 V	-	0.16	0.26	V
I_{LI}	input leakage current	$V_I = V_{CC}$ or GND; V_{CC} = 6.0 V	-	-	±0.1	µA
I_{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL}; $V_O = V_{CC}$ or GND; V_{CC} = 6.0 V	-	-	±0.5	µA
I_{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; I_O = 0 A; V_{CC} = 6.0 V	-	-	8.0	µA
C_i	input capacitance		-	3.5	-	pF
T_{amb} = –40 °C to +85 °C						
V_{IH}	HIGH-state input voltage	V_{CC} = 2.0 V	1.5	-	-	V
		V_{CC} = 4.5 V	3.15	-	-	V
		V_{CC} = 6.0 V	4.2	-	-	V
V_{IL}	LOW-state input voltage	V_{CC} = 2.0 V	-	-	0.5	V
		V_{CC} = 4.5 V	-	-	1.35	V
		V_{CC} = 6.0 V	-	-	1.8	V
V_{OH}	HIGH-state output voltage	$V_I = V_{IH}$ or V_{IL}				
		I_O = –20 µA; V_{CC} = 2.0 V	1.9	-	-	V
		I_O = –20 µA; V_{CC} = 4.5 V	4.4	-	-	V
		I_O = –20 µA; V_{CC} = 6.0 V	5.9	-	-	V
		I_O = –4.0 mA; V_{CC} = 4.5 V	3.84	-	-	V
		I_O = –5.2 mA; V_{CC} = 6.0 V	5.34	-	-	V
V_{OL}	LOW-state output voltage	$V_I = V_{IH}$ or V_{IL}				
		I_O = 20 µA; V_{CC} = 2.0 V	-	-	0.1	V
		I_O = 20 µA; V_{CC} = 4.5 V	-	-	0.1	V
		I_O = 20 µA; V_{CC} = 6.0 V	-	-	0.1	V
		I_O = 4.0 mA; V_{CC} = 4.5 V	-	-	0.33	V
		I_O = 5.2 mA; V_{CC} = 6.0 V	-	-	0.33	V
I_{LI}	input leakage current	$V_I = V_{CC}$ or GND; V_{CC} = 6.0 V	-	-	±1.0	µA

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Table 7: Static characteristics 74HC273 *...continued*

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL}; $V_O = V_{CC}$ or GND; V_{CC} = 6.0 V	-	-	±5.0	µA
I_{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; I_O = 0 A; V_{CC} = 6.0 V	-	-	80	µA
T_{amb} = −40 °C to +125 °C						
V_{IH}	HIGH-state input voltage	V_{CC} = 2.0 V	1.5	-	-	V
		V_{CC} = 4.5 V	3.15	-	-	V
		V_{CC} = 6.0 V	4.2	-	-	V
V_{IL}	LOW-state input voltage	V_{CC} = 2.0 V	-	-	0.5	V
		V_{CC} = 4.5 V	-	-	1.35	V
		V_{CC} = 6.0 V	-	-	1.8	V
V_{OH}	HIGH-state output voltage	$V_I = V_{IH}$ or V_{IL}		-		
		I_O = −20 µA; V_{CC} = 2.0 V	1.9	-	-	V
		I_O = −20 µA; V_{CC} = 4.5 V	4.4	-	-	V
		I_O = −20 µA; V_{CC} = 6.0 V	5.9	-	-	V
		I_O = −4.0 mA; V_{CC} = 4.5 V	3.7	-	-	V
		I_O = −5.2 mA; V_{CC} = 6.0 V	5.2	-	-	V
V_{OL}	LOW-state output voltage	$V_I = V_{IH}$ or V_{IL}		-		
		I_O = 20 µA; V_{CC} = 2.0 V	-	-	0.1	V
		I_O = 20 µA; V_{CC} = 4.5 V	-	-	0.1	V
		I_O = 20 µA; V_{CC} = 6.0 V	-	-	0.1	V
		I_O = 4.0 mA; V_{CC} = 4.5 V	-	-	0.4	V
		I_O = 5.2 mA; V_{CC} = 6.0 V	-	-	0.4	V
I_{LI}	input leakage current	$V_I = V_{CC}$ or GND; V_{CC} = 6.0 V	-	-	±1.0	µA
I_{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL}; $V_O = V_{CC}$ or GND; V_{CC} = 6.0 V	-	-	±10.0	µA
I_{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; I_O = 0 A; V_{CC} = 6.0 V	-	-	160	µA

Table 8: Static characteristics 74HCT273

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = 25 °C						
V_{IH}	HIGH-state input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V_{IL}	LOW-state input voltage	V_{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
V_{OH}	HIGH-state output voltage	$V_I = V_{IH}$ or V_{IL}; V_{CC} = 4.5 V				
		I_O = −20 µA	4.4	4.5	-	V
		I_O = −4.0 mA	3.98	4.32	-	V
V_{OL}	LOW-state output voltage	$V_I = V_{IH}$ or V_{IL}; V_{CC} = 4.5 V				
		I_O = 20 µA	-	0	0.1	V
		I_O = 4.0 mA	-	0.15	0.26	V
I_{LI}	input leakage current	$V_I = V_{CC}$ or GND; V_{CC} = 5.5 V	-	-	±0.1	µA

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Table 8: Static characteristics 74HCT273 *…continued*

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL}; V_{CC} = 5.5 V; $V_O = V_{CC}$ or GND per input pin; other inputs at V_{CC} or GND; I_O = 0 A	-	-	±0.5	µA
I_{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; I_O = 0 A; V_{CC} = 5.5 V	-	-	8.0	µA
ΔI_{CC}	additional quiescent supply current	$V_I = V_{CC}$ – 2.1 V; other inputs at V_{CC} or GND; V_{CC} = 4.5 V to 5.5 V; I_O = 0 A				
	pin $\overline{MR}$		-	100	360	µA
	pin CP		-	175	630	µA
	pin Dn		-	15	54	µA
C_i	input capacitance		-	3.5	-	pF
T_{amb} = –40 °C to +85 °C						
V_{IH}	HIGH-state input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V_{IL}	LOW-state input voltage	V_{CC} = 4.5 V to 5.5 V	-	-	0.8	V
V_{OH}	HIGH-state output voltage	$V_I = V_{IH}$ or V_{IL}; V_{CC} = 4.5 V				
		I_O = –20 µA	4.4	-	-	V
		I_O = –4.0 mA	3.84	-	-	V
V_{OL}	LOW-state output voltage	$V_I = V_{IH}$ or V_{IL}; V_{CC} = 4.5 V				
		I_O = 20 µA	-	-	0.1	V
		I_O = 4.0 mA	-	-	0.33	V
I_{LI}	input leakage current	$V_I = V_{CC}$ or GND; V_{CC} = 5.5 V	-	-	±1.0	µA
I_{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL}; V_{CC} = 5.5 V; $V_O = V_{CC}$ or GND per input pin; other inputs at V_{CC} or GND; I_O = 0 A	-	-	±5.0	µA
I_{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; I_O = 0 A; V_{CC} = 5.5 V	-	-	80	µA
ΔI_{CC}	additional quiescent supply current	$V_I = V_{CC}$ – 2.1 V; other inputs at V_{CC} or GND; V_{CC} = 4.5 V to 5.5 V; I_O = 0 A				
	pin $\overline{MR}$		-	-	450	µA
	pin CP		-	-	787.5	µA
	pin Dn		-	-	67.5	µA
T_{amb} = –40 °C to +125 °C						
V_{IH}	HIGH-state input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V_{IL}	LOW-state input voltage	V_{CC} = 4.5 V to 5.5 V	-	-	0.8	V
V_{OH}	HIGH-state output voltage	$V_I = V_{IH}$ or V_{IL}; V_{CC} = 4.5 V				
		I_O = –20 µA	4.4	-	-	V
		I_O = –4.0 mA	3.7	-	-	V
V_{OL}	LOW-state output voltage	$V_I = V_{IH}$ or V_{IL}; V_{CC} = 4.5 V				
		I_O = 20 µA	-	-	0.1	V
		I_O = 4.0 mA	-	-	0.4	V
I_{LI}	input leakage current	$V_I = V_{CC}$ or GND; V_{CC} = 5.5 V	-	-	±1.0	µA

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Table 8: Static characteristics 74HCT273 *…continued*

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL}; V_{CC} = 5.5 V; $V_O = V_{CC}$ or GND per input pin; other inputs at V_{CC} or GND; I_O = 0 A	-	-	±10	µA
I_{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; I_O = 0 A; V_{CC} = 5.5 V	-	-	160	µA
ΔI_{CC}	additional quiescent supply current	$V_I = V_{CC}$ – 2.1 V; other inputs at V_{CC} or GND; V_{CC} = 4.5 V to 5.5 V; I_O = 0 A				
	pin $\overline{MR}$		-	-	490	µA
	pin CP		-	-	857.5	µA
	pin Dn		-	-	73.5	µA

11. Dynamic characteristics

Table 9: Dynamic characteristics 74HC273

Voltages are referenced to GND (ground = 0 V); $t_r = t_f$ = 6 ns; C_L = 50 pF unless otherwise specified; for test circuit see Figure 10.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = 25 °C						
t_{PHL}, t_{PLH}	propagation delay CP to Qn	see Figure 7				
		V_{CC} = 2.0 V	-	41	150	ns
		V_{CC} = 4.5 V	-	15	30	ns
		V_{CC} = 5 V; C_L = 15 pF	-	15	-	ns
		V_{CC} = 6.0 V	-	13	26	ns
t_{PHL}	HIGH-to-LOW propagation delay $\overline{MR}$ to Qn	see Figure 8				
		V_{CC} = 2.0 V	-	44	150	ns
		V_{CC} = 4.5 V	-	16	30	ns
		V_{CC} = 5 V; C_L = 15 pF	-	15	-	ns
		V_{CC} = 6.0 V	-	14	26	ns
t_{THL}, t_{TLH}	output transition time	see Figure 7				
		V_{CC} = 2.0 V	-	19	75	ns
		V_{CC} = 4.5 V	-	7	15	ns
		V_{CC} = 6.0 V	-	6	13	ns
t_W	pulse width					
	clock HIGH or LOW	see Figure 7				
		V_{CC} = 2.0 V	80	14	-	ns
		V_{CC} = 4.5 V	16	5	-	ns
		V_{CC} = 6.0 V	14	4	-	ns
	master reset LOW	see Figure 8				
		V_{CC} = 2.0 V	60	17	-	ns
		V_{CC} = 4.5 V	12	6	-	ns
		V_{CC} = 6.0 V	10	5	-	ns

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Table 9: Dynamic characteristics 74HC273 *...continued*

Voltages are referenced to GND (ground = 0 V); $t_r = t_f$ = 6 ns; C_L = 50 pF unless otherwise specified; for test circuit see Figure 10.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
t_{rec}	recovery time $\overline{MR}$ to CP	see Figure 8					
		V_{CC} = 2.0 V		+50	–6	-	ns
		V_{CC} = 4.5 V		+10	–2	-	ns
		V_{CC} = 6.0 V		+9	–2	-	ns
t_{su}	set-up time Dn to CP	see Figure 9					
		V_{CC} = 2.0 V		60	11	-	ns
		V_{CC} = 4.5 V		12	4	-	ns
		V_{CC} = 6.0 V		10	3	-	ns
t_h	hold time Dn to CP	see Figure 9					
		V_{CC} = 2.0 V		+3	–6	-	ns
		V_{CC} = 4.5 V		+3	–2	-	ns
		V_{CC} = 6.0 V		+3	–2	-	ns
f_{max}	maximum input clock frequency	see Figure 7					
		V_{CC} = 2.0 V		6.0	20.6	-	MHz
		V_{CC} = 4.5 V		30	103	-	MHz
		V_{CC} = 5 V; C_L = 15 pF		-	66	-	MHz
		V_{CC} = 6.0 V		35	122	-	MHz
C_{PD}	power dissipation capacitance	per flip-flop; V_I = GND to V_{CC}	[1]	-	20	-	pF
T_{amb} = –40 °C to +85 °C							
t_{PHL}, t_{PLH}	propagation delay CP to Qn	see Figure 7					
		V_{CC} = 2.0 V		-	-	185	ns
		V_{CC} = 4.5 V		-	-	37	ns
		V_{CC} = 6.0 V		-	-	31	ns
t_{PHL}	HIGH-to-LOW propagation delay $\overline{MR}$ to Qn	see Figure 8					
		V_{CC} = 2.0 V		-	-	185	ns
		V_{CC} = 4.5 V		-	-	37	ns
		V_{CC} = 6.0 V		-	-	31	ns
t_{THL}, t_{TLH}	output transition time	see Figure 7					
		V_{CC} = 2.0 V		-	-	95	ns
		V_{CC} = 4.5 V		-	-	19	ns
		V_{CC} = 6.0 V		-	-	15	ns
t_W	pulse width						
	clock HIGH or LOW	see Figure 7					
		V_{CC} = 2.0 V		100	-	-	ns
		V_{CC} = 4.5 V		20	-	-	ns
		V_{CC} = 6.0 V		17	-	-	ns
	master reset LOW	see Figure 8					
		V_{CC} = 2.0 V		75	-	-	ns
		V_{CC} = 4.5 V		15	-	-	ns
		V_{CC} = 6.0 V		13	-	-	ns

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Table 9: Dynamic characteristics 74HC273 *...continued*

Voltages are referenced to GND (ground = 0 V); $t_r = t_f$ = 6 ns; C_L = 50 pF unless otherwise specified; for test circuit see Figure 10.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
t_{rec}	recovery time $\overline{MR}$ to CP	see Figure 8				
		V_{CC} = 2.0 V	65	-	-	ns
		V_{CC} = 4.5 V	13	-	-	ns
		V_{CC} = 6.0 V	11	-	-	ns
t_{su}	set-up time Dn to CP	see Figure 9				
		V_{CC} = 2.0 V	75	-	-	ns
		V_{CC} = 4.5 V	15	-	-	ns
		V_{CC} = 6.0 V	13	-	-	ns
t_h	hold time Dn to CP	see Figure 9				
		V_{CC} = 2.0 V	3	-	-	ns
		V_{CC} = 4.5 V	3	-	-	ns
		V_{CC} = 6.0 V	3	-	-	ns
f_{max}	maximum input clock frequency	see Figure 7				
		V_{CC} = 2.0 V	4.8	-	-	MHz
		V_{CC} = 4.5 V	24	-	-	MHz
		V_{CC} = 6.0 V	28	-	-	MHz
T_{amb} = −40 °C to +125 °C						
t_{PHL}, t_{PLH}	propagation delay CP to Qn	see Figure 7				
		V_{CC} = 2.0 V	-	-	225	ns
		V_{CC} = 4.5 V	-	-	45	ns
		V_{CC} = 6.0 V	-	-	38	ns
t_{PHL}	HIGH-to-LOW propagation delay $\overline{MR}$ to Qn	see Figure 8				
		V_{CC} = 2.0 V	-	-	225	ns
		V_{CC} = 4.5 V	-	-	45	ns
		V_{CC} = 6.0 V	-	-	38	ns
t_{THL}, t_{TLH}	output transition time	see Figure 7				
		V_{CC} = 2.0 V	-	-	110	ns
		V_{CC} = 4.5 V	-	-	22	ns
		V_{CC} = 6.0 V	-	-	19	ns
t_W	pulse width					
	clock HIGH or LOW	see Figure 7				
		V_{CC} = 2.0 V	120	-	-	ns
		V_{CC} = 4.5 V	24	-	-	ns
		V_{CC} = 6.0 V	20	-	-	ns
	master reset LOW	see Figure 8				
		V_{CC} = 2.0 V	90	-	-	ns
		V_{CC} = 4.5 V	18	-	-	ns
		V_{CC} = 6.0 V	15	-	-	ns

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Table 9: Dynamic characteristics 74HC273 *...continued*

Voltages are referenced to GND (ground = 0 V); $t_r = t_f$ = 6 ns; C_L = 50 pF unless otherwise specified; for test circuit see Figure 10.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
t_{rec}	recovery time $\overline{MR}$ to CP	see Figure 8				
		V_{CC} = 2.0 V	75	-	-	ns
		V_{CC} = 4.5 V	15	-	-	ns
		V_{CC} = 6.0 V	13	-	-	ns
t_{su}	set-up time Dn to CP	see Figure 9				
		V_{CC} = 2.0 V	90	-	-	ns
		V_{CC} = 4.5 V	18	-	-	ns
		V_{CC} = 6.0 V	15	-	-	ns
t_h	hold time Dn to CP	see Figure 9				
		V_{CC} = 2.0 V	3	-	-	ns
		V_{CC} = 4.5 V	3	-	-	ns
		V_{CC} = 6.0 V	3	-	-	ns
f_{max}	maximum input clock frequency	see Figure 7				
		V_{CC} = 2.0 V	4.0	-	-	MHz
		V_{CC} = 4.5 V	20	-	-	MHz
		V_{CC} = 6.0 V	24	-	-	MHz

[1] C_{PD} is used to determine the dynamic power dissipation (P_D in µW).
$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:
f_i = input frequency in MHz;
f_o = output frequency in MHz;
C_L = output load capacitance in pF;
V_{CC} = supply voltage in V;
N = number of inputs switching;
$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

Table 10: Dynamic characteristics 74HCT273

Voltages are referenced to GND (ground = 0 V); $t_r = t_f$ = 6 ns; C_L = 50 pF unless otherwise specified; for test circuit see Figure 10.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = 25 °C						
t_{PHL}, t_{PLH}	propagation delay CP to Qn	see Figure 7				
		V_{CC} = 4.5 V	-	16	30	ns
		V_{CC} = 5 V; C_L = 15 pF	-	15	-	ns
t_{PHL}	HIGH-to-LOW propagation delay $\overline{MR}$ to Qn	see Figure 8				
		V_{CC} = 4.5 V	-	23	34	ns
		V_{CC} = 5 V; C_L = 15 pF	-	20	-	ns
t_{THL}, t_{TLH}	output transition time	V_{CC} = 4.5 V; see Figure 7	-	7	15	ns
t_W	pulse width					
	clock HIGH or LOW	V_{CC} = 4.5 V; see Figure 7	16	9	-	ns
	master reset LOW	V_{CC} = 4.5 V; see Figure 8	16	8	-	ns

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Table 10: Dynamic characteristics 74HCT273 *…continued*

Voltages are referenced to GND (ground = 0 V); $t_r = t_f$ = 6 ns; C_L = 50 pF unless otherwise specified; for test circuit see Figure 10.

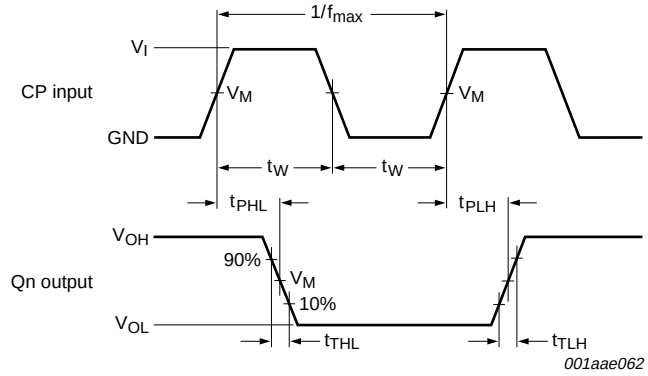
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
t_{rec}	recovery time $\overline{MR}$ to CP	V_{CC} = 4.5 V; see Figure 8		+10	–2	-	ns
t_{su}	set-up time Dn to CP	V_{CC} = 4.5 V; see Figure 9		12	5	-	ns
t_h	hold time Dn to CP	V_{CC} = 4.5 V; see Figure 9		+3	–4	-	ns
f_{max}	maximum input clock frequency	see Figure 7					
		V_{CC} = 4.5 V		30	56	-	MHz
		V_{CC} = 5.0 V; C_L = 15 pF		-	36	-	MHz
C_{PD}	power dissipation capacitance	per flip-flop; V_I = GND to (V_{CC} – 1.5 V)	[1]	-	23	-	pF
T_{amb} = –40 °C to +85 °C							
t_{PHL}, t_{PLH}	propagation delay CP to Qn	V_{CC} = 4.5 V; see Figure 7		-	-	38	ns
t_{PHL}	HIGH-to-LOW propagation delay $\overline{MR}$ to Qn	V_{CC} = 4.5 V; see Figure 8		-	-	43	ns
t_{THL}, t_{TLH}	output transition time	V_{CC} = 4.5 V; see Figure 7		-	-	19	ns
t_W	pulse width						
	clock HIGH or LOW	V_{CC} = 4.5 V; see Figure 7		20	-	-	ns
	master reset LOW	V_{CC} = 4.5 V; see Figure 8		20	-	-	ns
t_{rec}	recovery time $\overline{MR}$ to CP	V_{CC} = 4.5 V; see Figure 8		13	-	-	ns
t_{su}	set-up time Dn to CP	V_{CC} = 4.5 V; see Figure 9		15	-	-	ns
t_h	hold time Dn to CP	V_{CC} = 4.5 V; see Figure 9		3	-	-	ns
f_{max}	maximum input clock frequency	V_{CC} = 4.5 V; see Figure 7		24	-	-	MHz
T_{amb} = –40 °C to +125 °C							
t_{PHL}, t_{PLH}	propagation delay CP to Qn	V_{CC} = 4.5 V; see Figure 7		-	-	45	ns
t_{PHL}	HIGH-to-LOW propagation delay $\overline{MR}$ to Qn	V_{CC} = 4.5 V; see Figure 8		-	-	51	ns
t_{THL}, t_{TLH}	output transition time	V_{CC} = 4.5 V; see Figure 7		-	-	22	ns
t_W	pulse width						
	clock HIGH or LOW	V_{CC} = 4.5 V; see Figure 7		24	-	-	ns
	master reset LOW	V_{CC} = 4.5 V; see Figure 8		24	-	-	ns
t_{rec}	recovery time $\overline{MR}$ to CP	V_{CC} = 4.5 V; see Figure 8		15	-	-	ns
t_{su}	set-up time Dn to CP	V_{CC} = 4.5 V; see Figure 9		18	-	-	ns
t_h	hold time Dn to CP	V_{CC} = 4.5 V; see Figure 9		3	-	-	ns
f_{max}	maximum input clock frequency	V_{CC} = 4.5 V; see Figure 7		20	-	-	MHz

[1] C_{PD} is used to determine the dynamic power dissipation (P_D in µW).
$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:
f_i = input frequency in MHz;
f_o = output frequency in MHz;
C_L = output load capacitance in pF;
V_{CC} = supply voltage in V;
N = number of inputs switching;

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$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

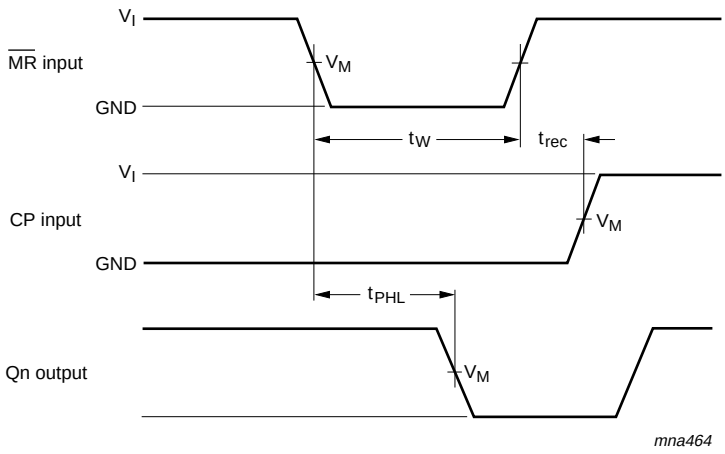
12. Waveforms



Measurement points are given in Table 11.

V_{OL} and V_{OH} are typical voltage output drop that occur with the output load.

Fig 7. Propagation delay clock input (CP) to output (Qn), clock (CP) pulse width, output transition time and the maximum clock pulse frequency

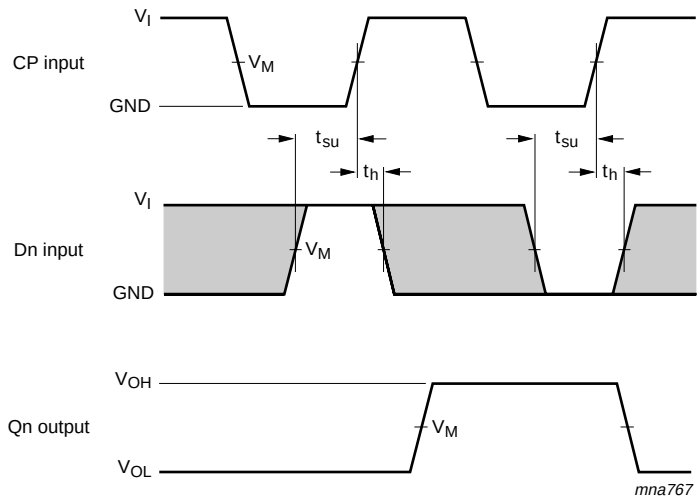


Measurement points are given in Table 11.

V_{OL} and V_{OH} are typical voltage output drop that occur with the output load.

Fig 8. Propagation delay master reset ($\overline{MR}$) to output (Qn), pulse width master reset ($\overline{MR}$) and recovery time master reset ($\overline{MR}$) to clock (CP)

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Measurement points are given in Table 11.

The shaded areas indicate when the input is permitted to change for predictable output performance.

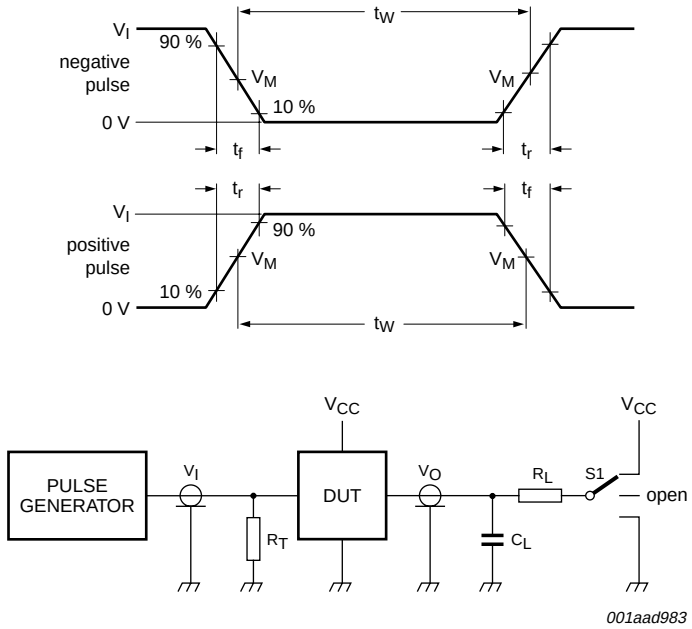
V_{OL} and V_{OH} are typical voltage output drop that occur with the output load.

Fig 9. Data set-up and hold times data input (Dn)

Table 11: Measurement points

Type	Input	Output
	V_M	V_M
74HC273	$0.5V_{CC}$	$0.5V_{CC}$
74HCT273	1.3 V	1.3 V

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Test data is given in Table 12.

Definitions test circuit:

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator

C_L = Load capacitance including jig and probe capacitance

R_L = Load resistor

S1 = Test selection switch

Fig 10. Load circuitry for measuring switching times

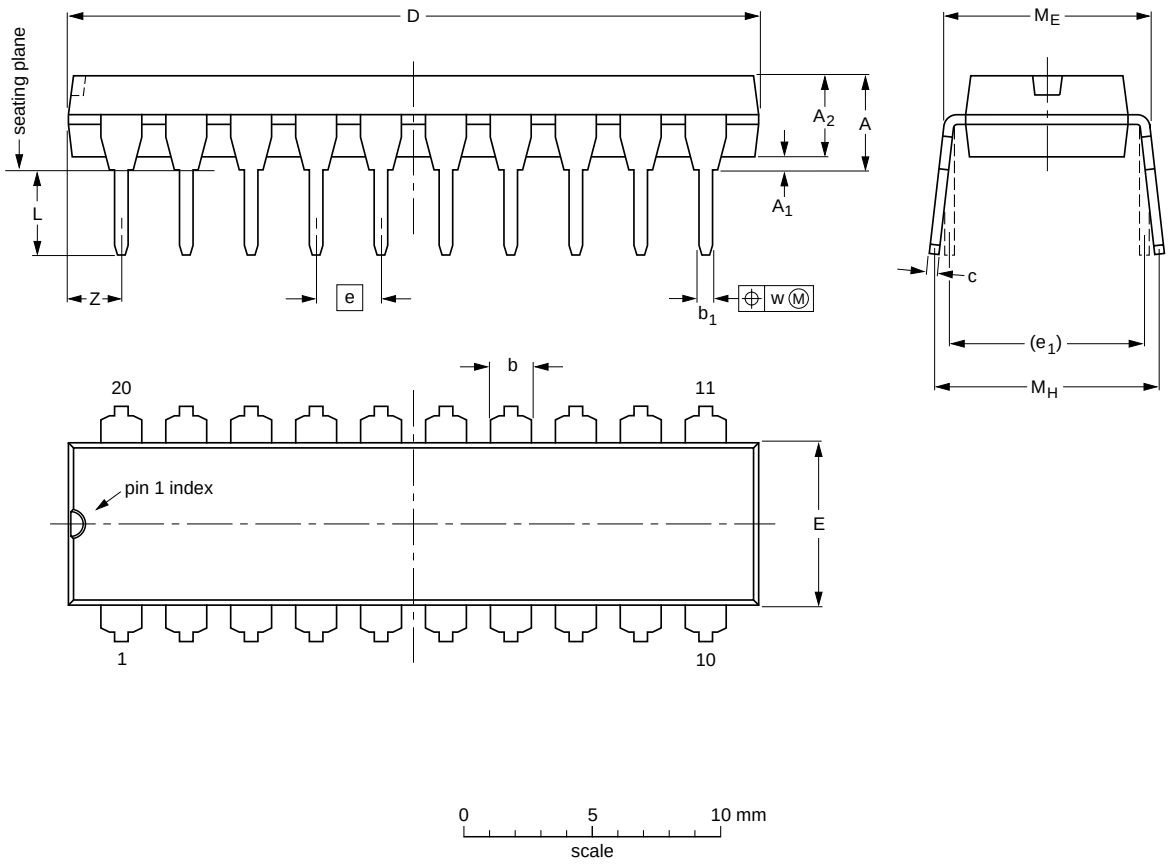
Table 12: Test data

Type	Input		Load		S1 position		
	V_I	t_r, t_f	C_L	R_L	t_{PHL}, t_{PLH}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}
74HC273	V_{CC}	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V_{CC}
74HCT273	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V_{CC}

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13. Package outline

DIP20: plastic dual in-line package; 20 leads (300 mil) **SOT146-1**



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A_1 min.	A_2 max.	b	b_1	c	D (1)	E (1)	e	e_1	L	M_E	M_H	w	Z (1) max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

Note

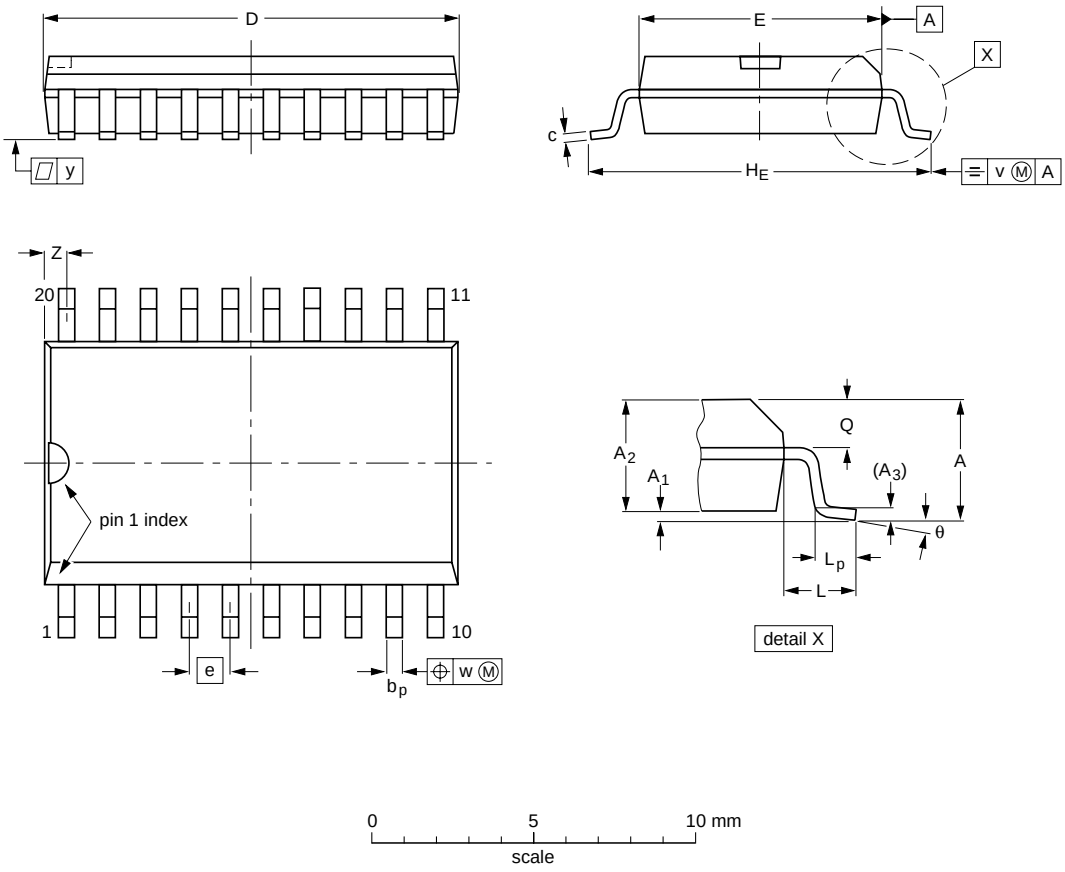
1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT146-1		MS-001	SC-603			~~99-12-27~~ 03-02-13

Fig 11. Package outline SOT146-1 (DIP20)

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SO20: plastic small outline package; 20 leads; body width 7.5 mm **SOT163-1**



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A_1	A_2	A_3	b_p	c	D (1)	E (1)	e	H_E	L	L_p	Q	v	w	y	Z (1)	θ
mm	2.65	0.3 0.1	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8^o 0^o
inches	0.1	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.05	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	

Note

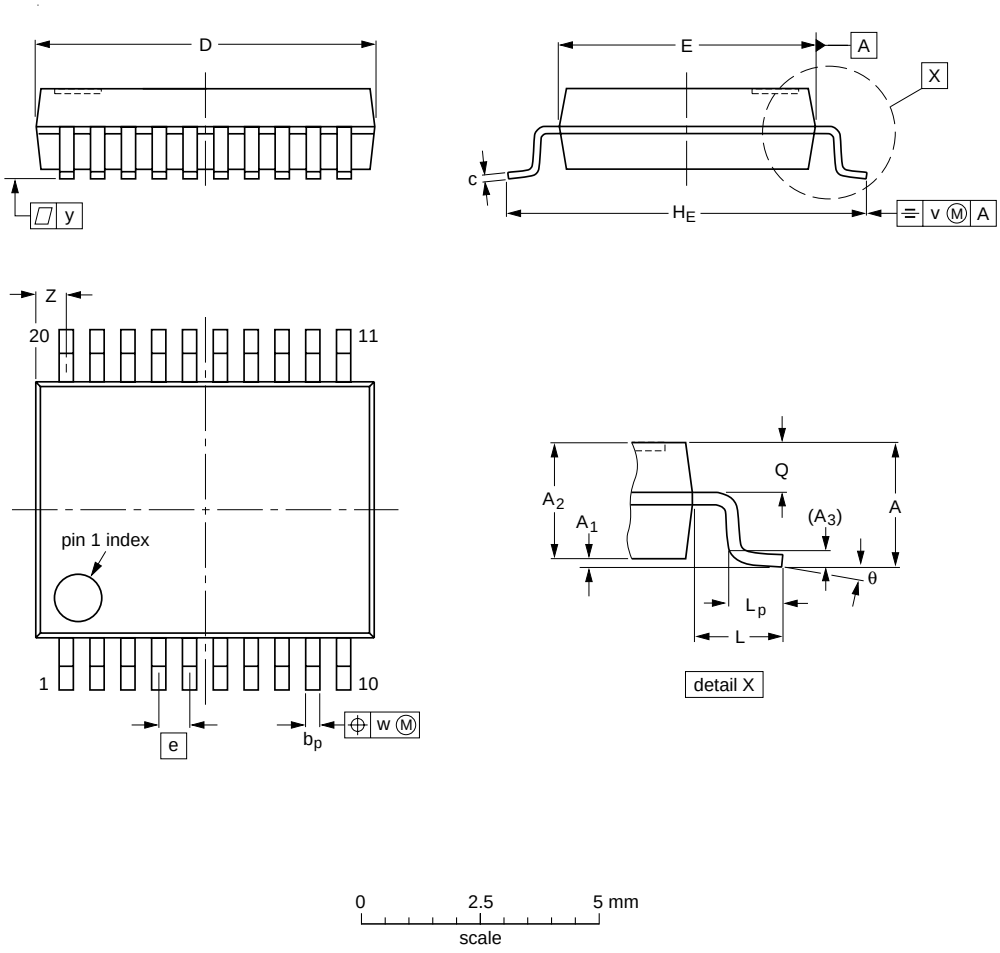
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT163-1	075E04	MS-013				~~99-12-27~~ 03-02-19

Fig 12. Package outline SOT163-1 (SO20)

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SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm **SOT339-1**



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A_1	A_2	A_3	b_p	c	$D^{(1)}$	$E^{(1)}$	e	H_E	L	L_p	Q	v	w	y	$Z^{(1)}$	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	7.4 7.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.9 0.5	8^o 0^o

Note

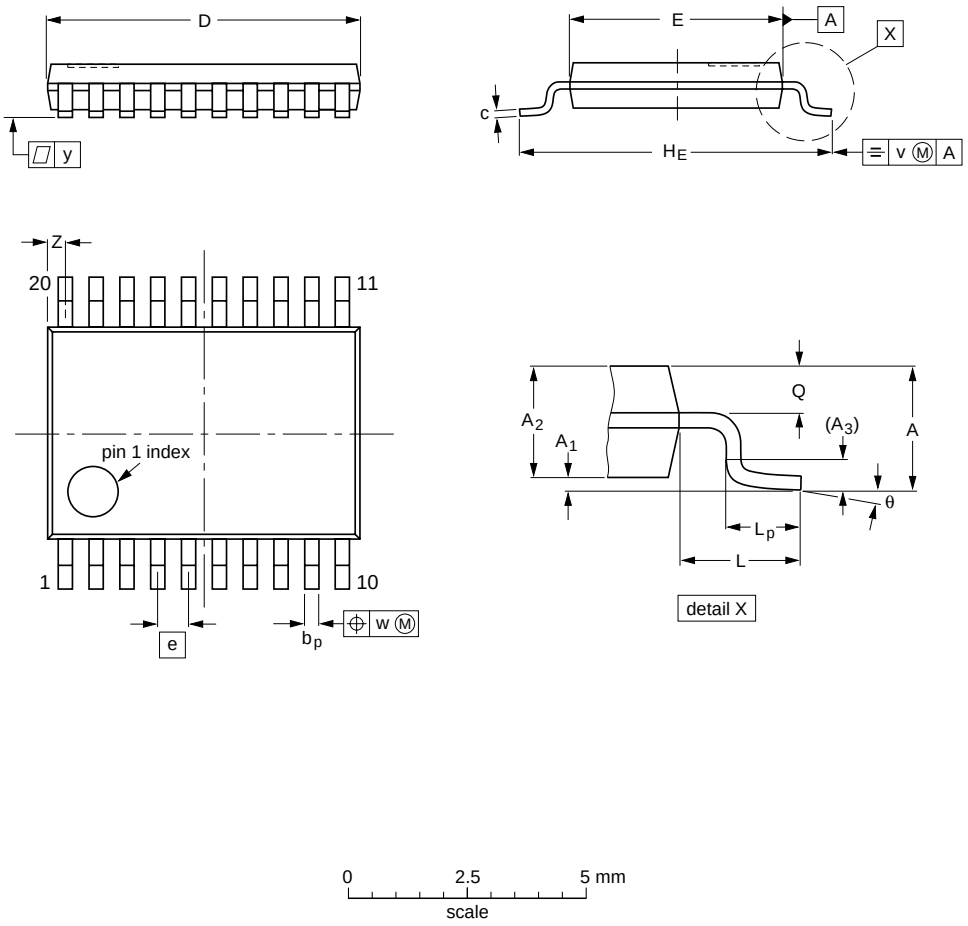
1. Plastic or metal protrusions of 0.2 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT339-1		MO-150				~~99-12-27~~ 03-02-19

Fig 13. Package outline SOT339-1 (SSOP20)

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TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm **SOT360-1**



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A_1	A_2	A_3	b_p	c	D (1)	E (2)	e	H_E	L	L_p	Q	v	w	y	Z (1)	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8^o 0^o

Notes

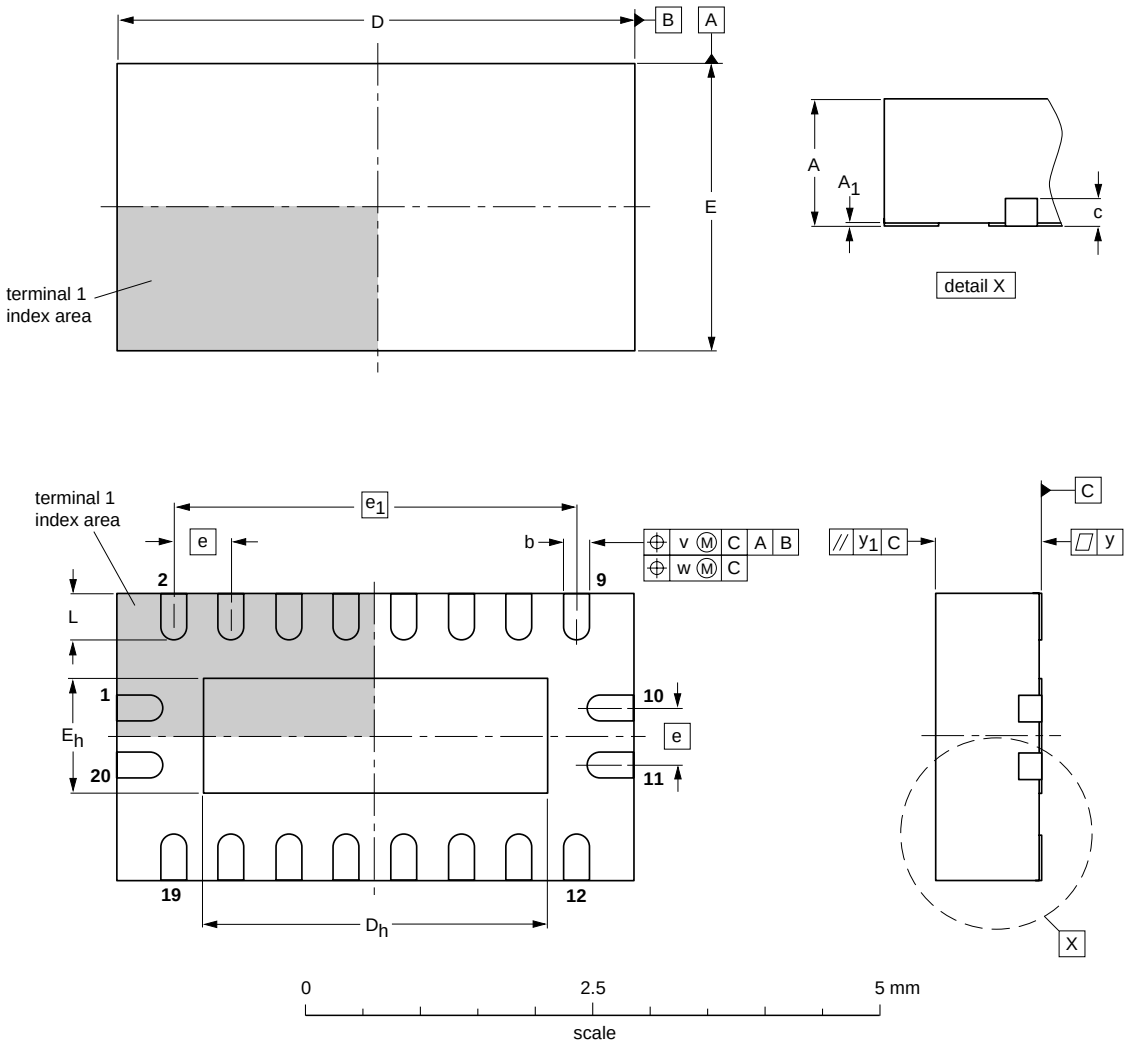
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT360-1		MO-153				~~99-12-27~~ 03-02-19

Fig 14. Package outline SOT360-1 (TSSOP20)

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DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 x 4.5 x 0.85 mm **SOT764-1**



DIMENSIONS (mm are the original dimensions)

UNIT	A(1) max.	A_1	b	c	D(1)	D_h	E(1)	E_h	e	e_1	L	v	w	y	y_1
mm	1	0.05 0.00	0.30 0.18	0.2	4.6 4.4	3.15 2.85	2.6 2.4	1.15 0.85	0.5	3.5	0.5 0.3	0.1	0.05	0.05	0.1

Note

1. Plastic or metal protrusions of 0.075 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT764-1	- - -	MO-241	- - -			~~02-10-17~~ 03-01-27

Fig 15. Package outline SOT764-1 (DHVQFN20)

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14. Abbreviations

Table 13: Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
LSTTL	Low-power Schottky Transistor-Transistor Logic
MM	Machine Model
MOS	Metal Oxide Semiconductor

15. Revision history

Table 14: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
74HC_HCT273_3	20060124	Product data sheet	-	-	74HC_HCT273_CNV_2
Modifications:	• The format of this data sheet has been redesigned to comply with the new presentation and information standard of Philips Semiconductors. • Section 4 “Ordering information”, Section 6 “Pinning information” and Section 13 “Package outline”: Added DHVQFN package information • Section 10 “Static characteristics”: Added from the family specification				
74HC_HCT273_CNV_2	19970827	Product specification	-	-	-

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16. Data sheet status

Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

17. Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Date of release: 24 January 2006
Document number: 74HC_HCT273_3

Published in The Netherlands

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